## nexperia

## **Quarterly Reliability Monitoring Results**

Quarters: Q1/2021 to Q4/2021

Based on structural similarity

Supplier		User Part Number						
Nexperia B.V. Name of Laboratory Assembly reliability labs Based on AEC-Q101 Test		PDTC115TM Part Description						
								Nexperia DHAM Small Signal Bipolar Transistor
		MCD package						
		Test Conditions	Duration	# Lots	# Quantity	# Rejects		
			TEST					
	Pre- and Post-Stress							
# E1	Electrical Test	Tamb = 25 °C	N/A	see below	all parts	see below		
		JESD22-A113 Bake Tamb = 125 °C	24 hours					
	PC	Bake Tamb = $125 ^{\circ}$ C Soak Tamb = $85 ^{\circ}$ C, RH = $85\%$	24 nours 168 hours					
# A1	Preconditioning	Reflow soldering	3 cycles	208	16640	0		
# AI		MIL-STD-750-1	-,	200	20010	~		
	HTRB	M1039 Method A						
	High Temperature Reverse	Tj = Tjmax, Vr = 100% of max. datasheet						
# B1	Bias	reverse voltage	1000 hours	202	16160	0		
	тс	JESD22-A104						
# A4	Temperature Cycling	-65 °C to Tjmax, not to exceed 150°C	1000 cycles	52	4160	0		
		JESD22-A102						
" • • • •	<b>AC</b> Autoclave	Tamb = 121 °C, RH = 100 % Pressure = 205 kPa (29.7 psia)	0.5.1	50				
# A3 alt	Autociave	Pressure = 203  kPa (29.7  psia)	96 hours	52	4160	0		
	H3TRB	JESD22-A101						
	High Humidity High	Tamb = $85 ^{\circ}$ C, RH = $85\%$ , VR = $80\%$ of						
# A2 alt	Temperature Reverse Bias		1000 hours	52	4160	0		
" AZ dit		MIL-STD-750 Method 1037	1000 110015	02	.100			
	IOL	ton = toff, devices powered to insure $\Delta T_j$ =						
# A5	Intermittent Operating Life		1000 hours	52	4160	0		
	RSH	JESD22-A111						
# C8	Resistance to Solder Heat	260 °C ± 5 °C	10 s	n.a.	n.a.	n.a.		
	SD							
# C10	Solderability	J-STD-002		111	1110	0		

[1] The maximum applied voltage is limited by test chamber set up and does not exceed 115V.

## **Calculation of FIT and MTTF**

Test considered for FIT calculation: High Temperature Reverse Bias (HTRB, Test #B1) Confidence level 60%, derated to 55 °C, activation energy 0.7 eV, test time 168 to 1000 hours

Wafer Fab	Technology	Quantity	Rejects	Failure Rate (FIT)	MTTF (hrs)
Nexperia DHAM	Small Signal Bipolar Transistor	16160	0	0.26	3.81E+09

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